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INIT		N DI	SOLOCUEE	Application Number	10/654,561		
	_		SCLOSURE	Filing Date	03 September 2003 (herewith)		
STATEMENT BY APPLICANT				First Named Inventor	Shahram Abdollahi-Alibeik et al.		
				Group Art Unit			
	(use as many s	heets as	necessary)	Examiner Name			
Sheet	1	of	3	Attorney Docket Number	TRAM 1002-1		

		<u> </u>	U.S. PATENT DOC	JMENTS	-
Examiner Initials	Cite No.1	U.S. Patent Document Kind Code Number (if known	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Attorney Docket Number

				U.S. PATENT DOCI	JMENTS	
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				Application Number			
INFO	INFORMATION DISCLOSUR		CLOSURE	Filing Date	03 September 2003 (herewith)		
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Sheet	3	of	3	Attorney Docket Number	TRAM 1002-1		

		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS	
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